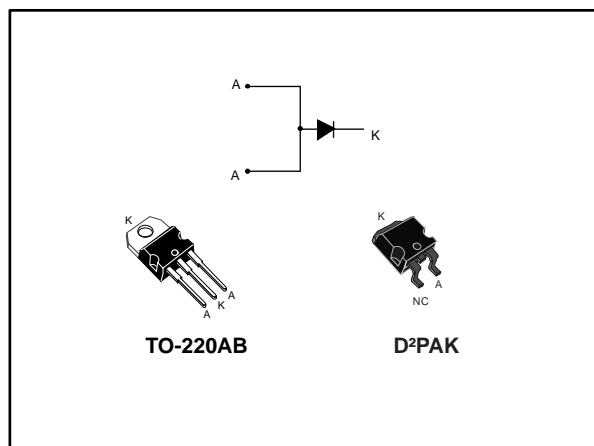


100 V field-effect rectifier diode

Datasheet - production data



Description

The device is based on a proprietary technology that achieves the best in class V_F/I_R trade-off for a given silicon surface. This 100 V rectifier has been optimized for use in confined applications where both efficiency and thermal performance are key. With a lower dependency of leakage current (I_R) and forward voltage (V_F) in function of temperature, the thermal runaway risk is reduced. It is highly recommended to be used in adapters and chargers.

Table 1: Device summary

Symbol	Value
$I_{F(AV)}$	40 A
V_{RRM}	100 V
V_F (max.)	0.375 V
I_R (max.)	190 μ A
T_j (max.)	175 °C

Features

- ST advanced rectifier process
- Stable leakage current over reverse voltage
- Reduced leakage current
- Low forward voltage drop
- High frequency operation

1 Characteristics

Table 2: Absolute ratings (limiting values at 25 °C, unless otherwise specified, with anode terminals short circuited)

Symbol	Parameter	Value	Unit	
V _{RRM}	Repetitive peak reverse voltage	100	V	
I _{F(RMS)}	Forward rms current	60	A	
I _{F(AV)}	Average forward current $\delta = 0.5$, square wave	T _C = 145 °C	40	A
I _{FSM}	Surge non repetitive forward current	t _p = 10 ms sinusoidal	440	A
T _{stg}	Storage temperature range	-65 to +175	°C	
T _j	Maximum operating junction temperature ⁽¹⁾	+175	°C	

Notes:

⁽¹⁾(dP_{tot}/dT_j) < (1/R_{th(j-a)}) condition to avoid thermal runaway for a diode on its own heatsink.

Table 3: Thermal resistance parameters

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case	0.8	°C/W

Table 4: Static electrical characteristics with anode terminals short circuited

Symbol	Parameter	Test conditions	Min.	Typ.	Max.	Unit	
I _R ⁽¹⁾	Reverse leakage current	T _j = 25 °C	V _R = V _{RRM}	-		190	μA
		T _j = 125 °C		-	12	24	mA
		T _j = 125 °C	V _R = 70 V	-	6	12	
V _F ⁽²⁾	Forward voltage drop	T _j = 25 °C	I _F = 4 A	-	0.380	0.430	V
		T _j = 125 °C		-	0.325	0.375	
		T _j = 25 °C	I _F = 10 A	-	0.465	0.525	
		T _j = 125 °C		-	0.455	0.510	
		T _j = 25 °C	I _F = 20 A	-	0.600	0.675	
		T _j = 125 °C		-	0.550	0.600	
T _j = 125 °C	I _F = 40 A	-	0.645	0.705			

Notes:

⁽¹⁾Pulse test: t_p = 5 ms, $\delta < 2\%$

⁽²⁾Pulse test: t_p = 380 μs, $\delta < 2\%$

To evaluate the conduction losses use the following equation:

$$P = 0.420 \times I_{F(AV)} + 0.009 I_{F^2(RMS)}$$

1.1 Characteristics (curves)

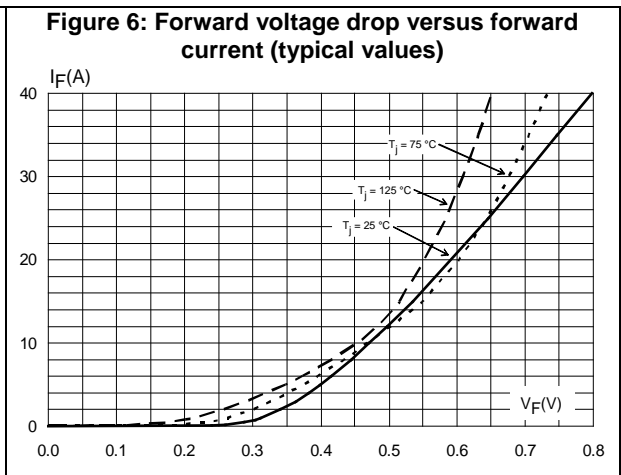
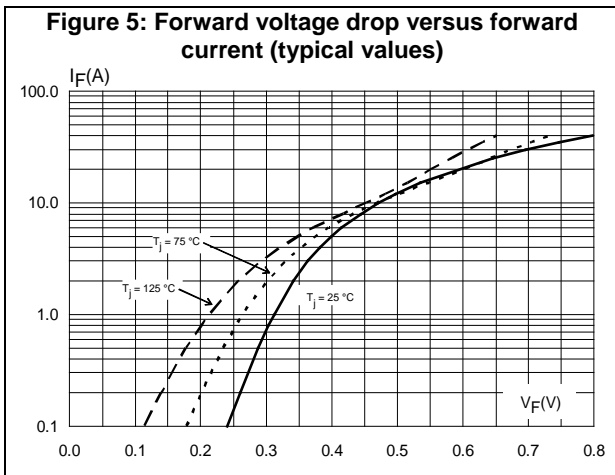
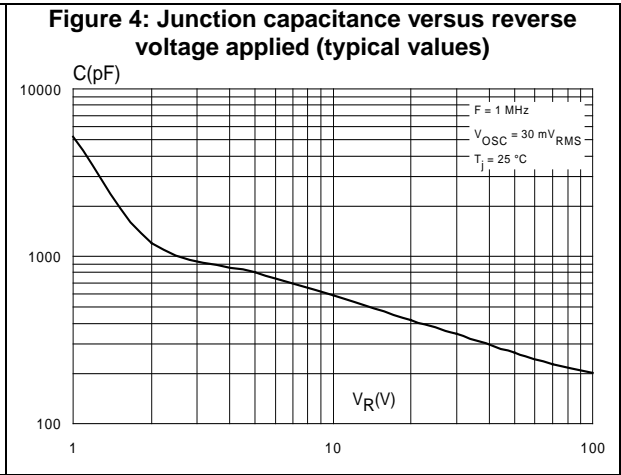
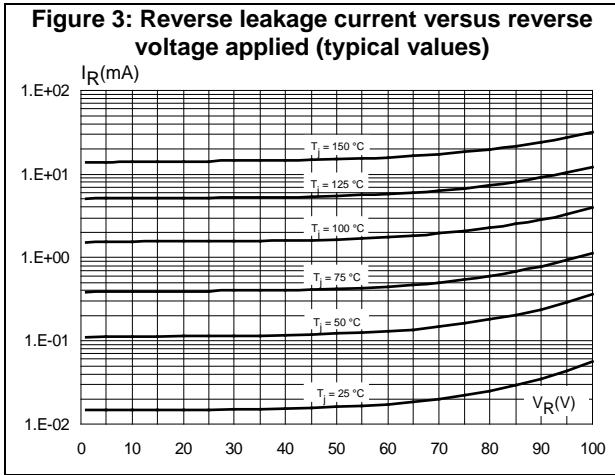
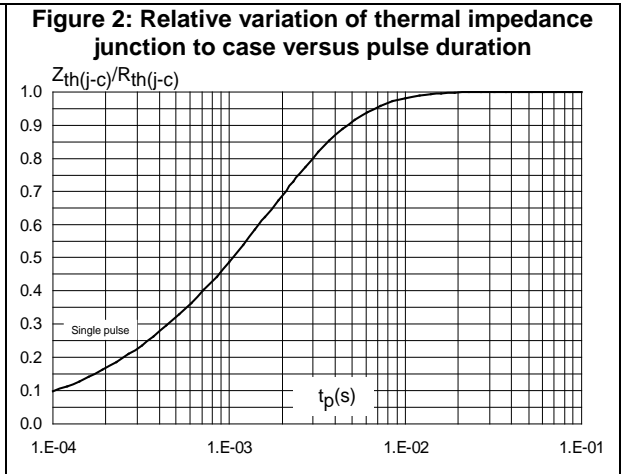
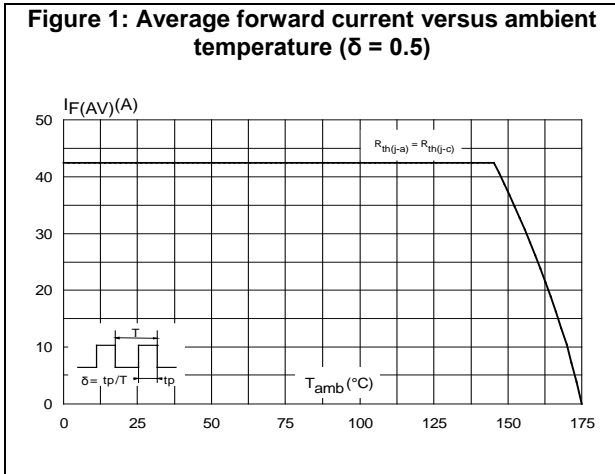
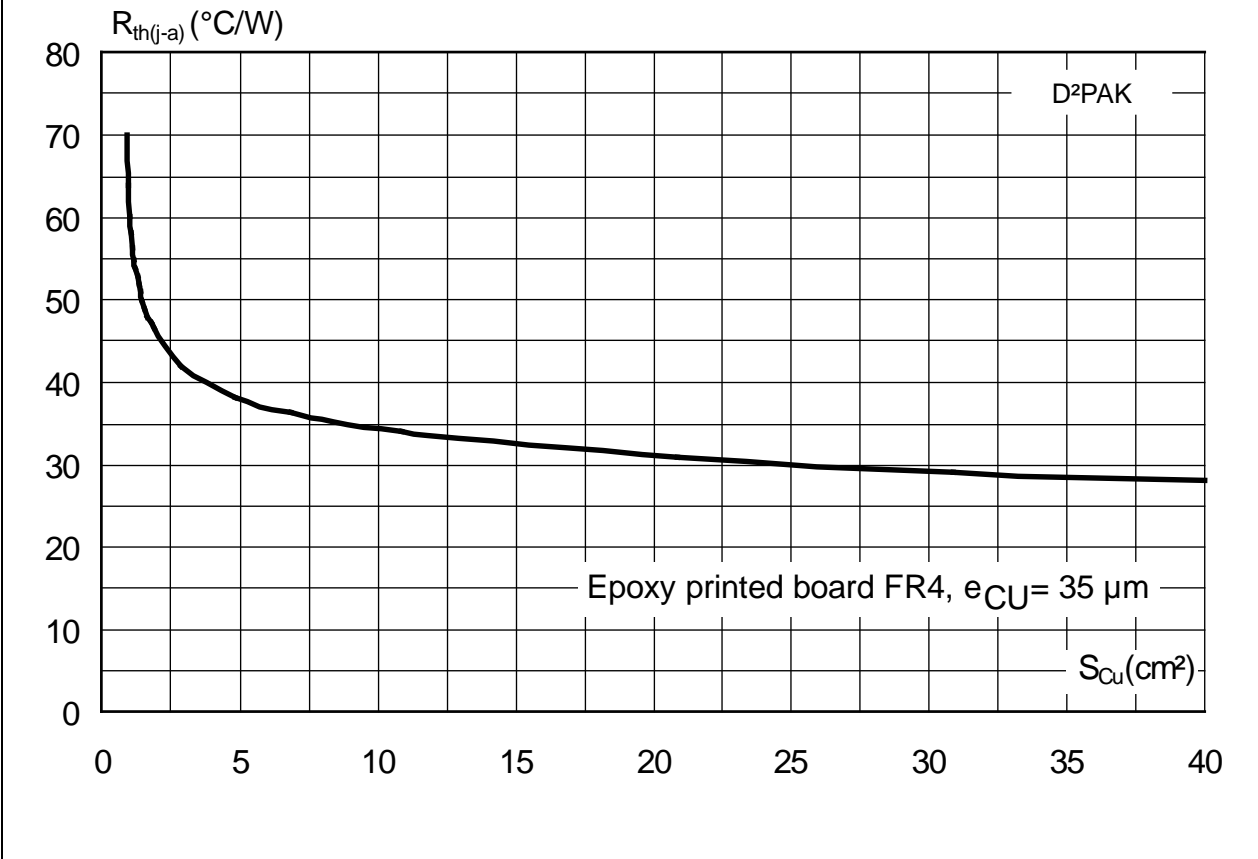


Figure 7: Thermal resistance junction to ambient versus copper surface under tab for D²PAK (typical values)



2 Package information

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK® packages, depending on their level of environmental compliance. ECOPACK® specifications, grade definitions and product status are available at: www.st.com. ECOPACK® is an ST trademark.

- Cooling method: by conduction (C)
- Epoxy meets UL 94,V0
- Recommended torque value: 0.55 N·m (for TO-220AB)
- Maximum torque value: 0.6 N·m (for TO-220AB)

2.1 TO-220AB package information

Figure 8: TO-220AB package outline

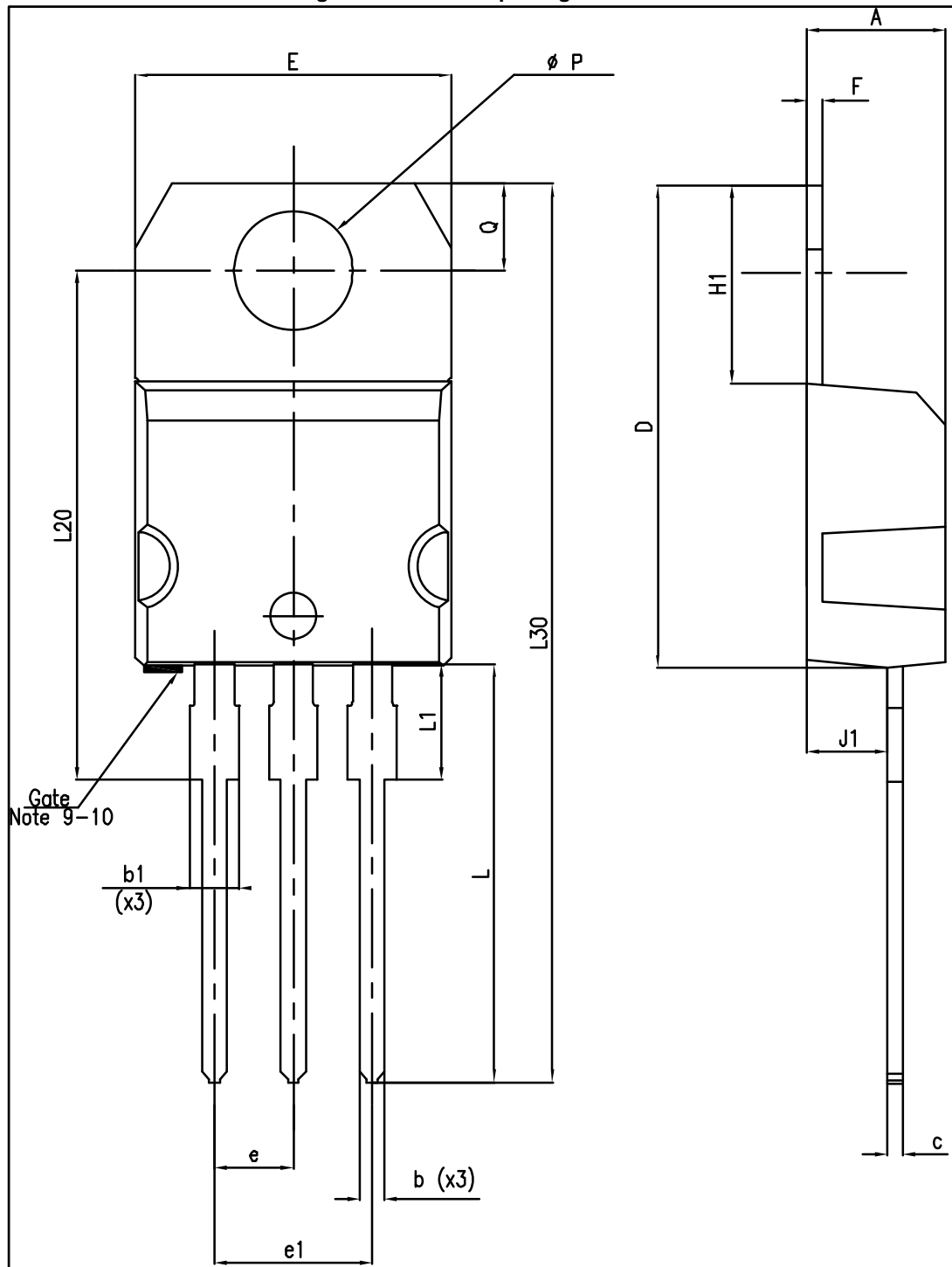


Table 5: TO-220AB package mechanical data

Ref.	Dimensions			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A	4.40	4.60	0.173	0.181
b	0.61	0.88	0.024	0.035
b1	1.14	1.70	0.045	0.067
c	0.48	0.70	0.019	0.028
D	15.25	15.75	0.600	0.620
E	10.00	10.40	0.394	0.409
e	2.40	2.70	0.094	0.106
e1	4.95	5.15	0.195	0.203
F	0.51	0.60	0.020	0.024
J1	2.40	2.72	0.094	0.107
H1	6.20	6.60	0.244	0.256
L	13.00	14.00	0.512	0.551
L1	3.50	3.93	0.138	0.155
L20	16.40 typ.		0.646 typ.	
L30	28.90 typ.		1.138	
Ø P	3.75	3.85	0.148	0.156
Q	2.65	2.95	0.104	0.116

2.2 D²PAK package information

Figure 9: D²PAK package outline

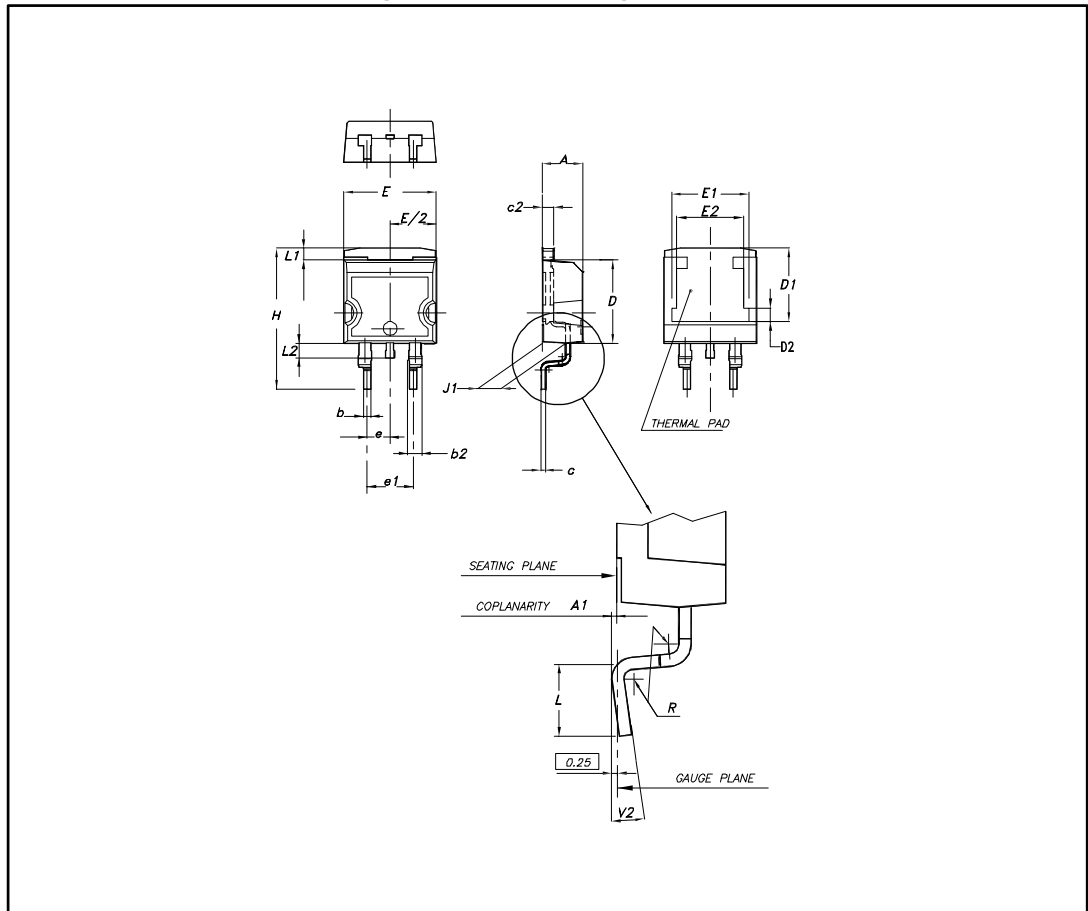
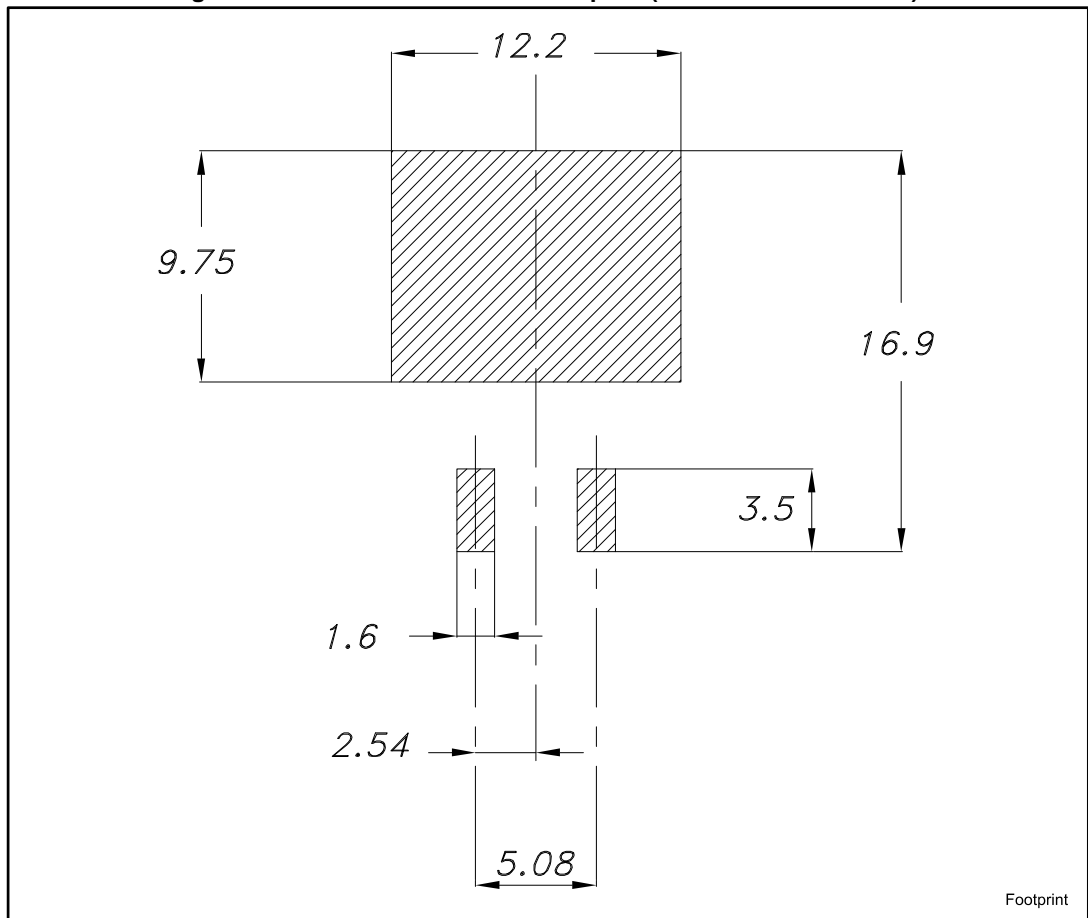


Table 6: D²PAK package mechanical data

Dim.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
A1	0.03		0.23	0.001		0.009
b	0.70		0.93	0.028		0.037
b2	1.14		1.70	0.045		0.067
c	0.45		0.60	0.018		0.024
c2	1.23		1.36	0.048		0.054
D	8.95		9.35	0.352		0.368
D1	7.50	7.75	8.00	0.295	0.305	0.315
D2	1.10	1.30	1.50	0.043	0.051	0.059
E	10		10.40	0.394		0.409
E1	8.50	8.70	8.90	0.335	0.343	0.350
E2	6.85	7.05	7.25	0.270	0.278	0.285
e		2.54			0.100	
e1	4.88		5.28	0.192		0.208
H	15		15.85	0.591		0.624
J1	2.49		2.69	0.098		0.106
L	2.29		2.79	0.090		0.110
L1	1.27		1.40	0.05		0.055
L2	1.30		1.75	0.051		0.069
R		0.4			0.016	
V2	0°		8°	0°		8°

Figure 10: D²PAK recommended footprint (dimensions are in mm)



Footprint

3 Ordering information

Table 7: Ordering information

Order code	Marking	Package	Weight	Base qty.	Delivery mode
FERD40H100STS	FD40H100STS	TO-220AB	1.38 g	50	Tube
FERD40H100SG-TR	FD40H100SG	D ² PAK	1.43 g	1000	Tape and reel

4 Revision history

Table 8: Document revision history

Date	Revision	Changes
08-Apr-2016	1	Initial release.

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